RS3G160AT

Pch -40V -16A Power MOSFET

Datasheet

V_{DSS}	-40V
R _{DS(on)} (Max.)	6.2mΩ
I _D	±16A
P _D	2.0W

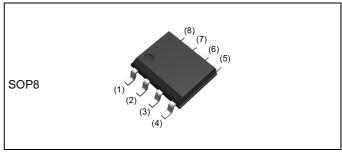
● Features

- 1) Low on resistance
- 2) Small surface mount package (SOP8)
- 3) Pb-free plating; RoHS compliant

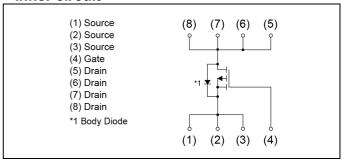
Application

Switching

Outline



•Inner circuit



Packaging specifications

- r dendening operations							
	Packing	Embossed Tape					
	Reel size (mm)	330					
Туре	Tape width (mm)	12					
	Quantity (pcs)	2500					
	Taping code	TB1					
	Marking	RS3G160AT					

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V _{DSS}	-40	V
Continuous drain current	I _D	±16	Α
Pulsed drain current	I _{DP} *1	±64	Α
Gate - Source voltage	V _{GSS}	±20	V
Avalanche current, single pulse	I _{AS} *2	-16	А
Avalanche energy, single pulse	E _{AS} *2	18	mJ
Douge dissination	P _D *3	2.0	W
Power dissipation	P _D *4	1.4	W
Junction temperature	T _j	150	°C
Operating junction and storage temperature range	T _{stg}	-55 to +150	°C

●Thermal resistance

Doromotor	Symbol -	Values			I India
Parameter		Min.	Тур.	Max.	Unit
Thermal registance innetion, ambient	R _{thJA} *3	-	-	62.5	°C/W
Thermal resistance, junction - ambient	R _{thJA} *4	-	-	89.2	°C/W

● Electrical characteristics (T_a = 25°C)

Darameter	Symbol Conditions		Values			Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = -1mA$	-40	-	-	V
Breakdown voltage temperature coefficient $\frac{\Delta V_{(BR)DSS}}{\Delta T_i} I_D = -1 mA$ referenced to 25°C			-	-22	-	mV/°C
Zero gate voltage drain current	I _{DSS}	V _{DS} = -40V, V _{GS} = 0V	-	-	-1	μA
Gate - Source leakage current	I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -1mA$	-1.0	-	-2.5	V
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$	I _D = -1mA referenced to 25°C	-	3.7	-	mV/°C
Static drain - source	D *5	V _{GS} = -10V, I _D = -16A	-	5.0	6.2	mO
on - state resistance	R _{DS(on)} *5	V _{GS} = -4.5V, I _D = -16A	-	6.1	7.6	mΩ
Gate resistance	R_G	f = 1MHz, open drain	-	1.9	-	Ω
Forward Transfer Admittance	Y _{fs} * ⁵	V _{DS} = -5V, I _D = -16A	28	-	-	S

^{*1} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*2} L \simeq 0.1mH, V_{DD} = -20V, R_G = 25 Ω , Starting T_j = 25 $^{\circ}$ C Fig.3-1,3-2

^{*3} Mounted on a ceramic board (30×30×0.8mm)

^{*4} Mounted on a Cu board (40×40×0.8mm)

^{*5} Pulsed

● Electrical characteristics (T_a = 25°C)

Daramatar	Cymahal	Conditions	Values			Unit
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit
Input capacitance	C _{iss}	V _{GS} = 0V	-	6250	-	
Output capacitance	C _{oss}	V _{DS} = -20V	-	710	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	540	-	
Turn - on delay time	t _{d(on)} *5	V _{DD} ≃ -20V,V _{GS} = -10V	-	24	-	
Rise time	t r*5	I _D = -8A	1	65	ı	no
Turn - off delay time	t _{d(off)} *5	$R_L \simeq 2.5\Omega$	-	260	-	ns
Fall time	t _f *5	$R_G = 10\Omega$	-	210	-	

• Gate charge characteristics $(T_a = 25^{\circ}C)$

Doromotor	Cymahal	Conditions		Values			l limit
Parameter	Symbol			Min.	Тур.	Max.	Unit
Total gate charge	O *5		V _{GS} = -10V	-	120.0	-	
Total gate charge	Q_g^{*5}	V _{DD} ≃ -20V I _D = -16A		-	55.0	-	0
Gate - Source charge	Q _{gs} *5		V _{GS} = -4.5V	-	19.0	-	nC
Gate - Drain charge	Q _{gd} *5			-	17.7	-	

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Darameter	Cumbal	Conditions	Values			Unit
Parameter	rameter Symbol Conditions		Min.	Тур.	Max.	Offic
Continuous forward current	I _S	T = 25°C	1	-	-1.67	Α
Pulse forward current	I _{SP} *1	T _a = 25°C	-	-	-64	Α
Forward voltage	V _{SD} *5	V _{GS} = 0V, I _S = -1.67A	-	-	-1.2	V
Reverse recovery time	t _{rr} *5	I _S = -16A, V _{GS} =0V	-	39	-	ns
Reverse recovery charge	Q _{rr} *5	di/dt = 100A/μs	-	36	-	nC

Fig.1 Power Dissipation Derating Curve

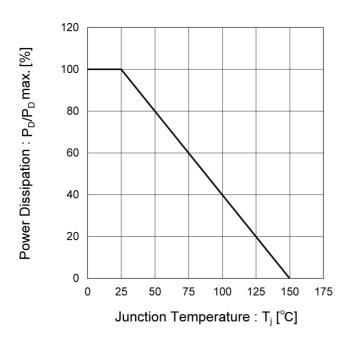
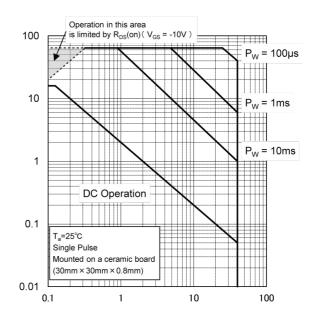


Fig.2 Maximum Safe Operating Area



Drain Current: -l_D [A]

Drain - Source Voltage : -V_{DS} [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

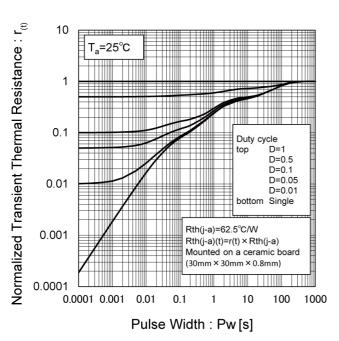


Fig.4 Single Pulse Maximum Power Dissipation

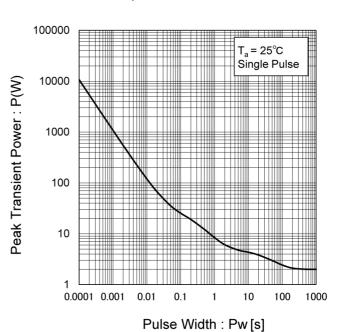
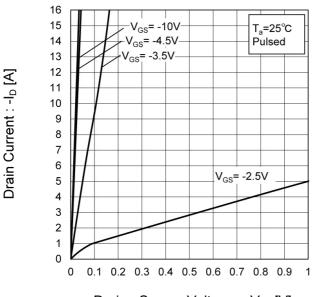
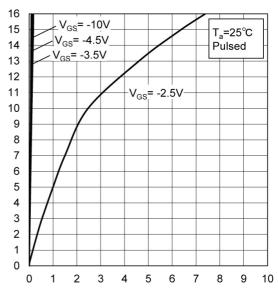


Fig.5 Typical Output Characteristics(I)



Drain - Source Voltage : -V_{DS} [V]

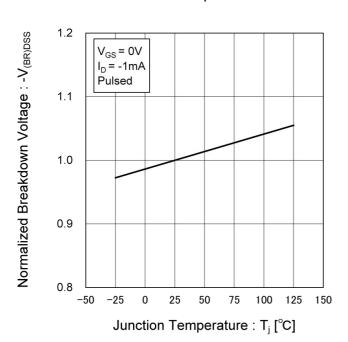
Fig.6 Typical Output Characteristics(II)



Drain Current : -I_D [A]

Drain - Source Voltage : -V_{DS} [V]

Fig.7 Breakdown Voltage vs.
Junction Temperature



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Fig.8 Typical Transfer Characteristics

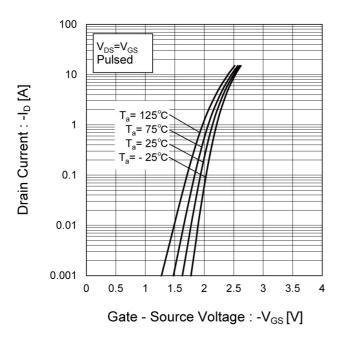


Fig.9 Gate Threshold Voltage vs.
Junction Temperature

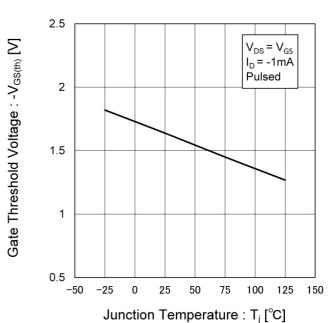


Fig.10 Forward Transfer Admittance vs.
Drain Current

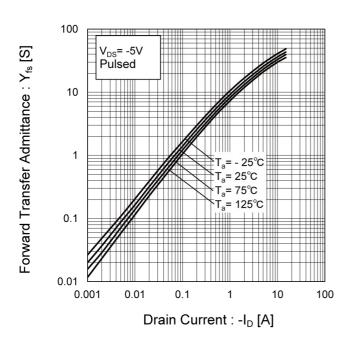


Fig.11 Drain Current Derating Curve

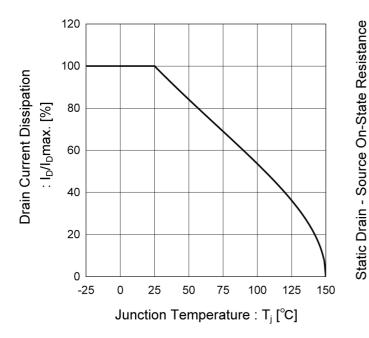


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

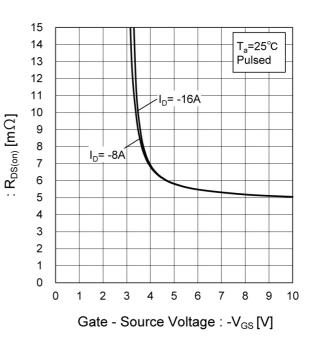


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

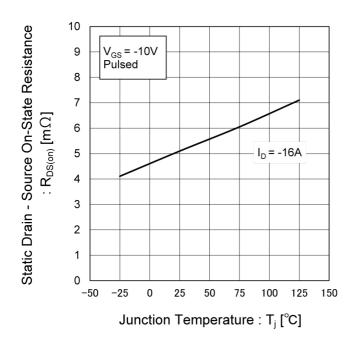


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (I)

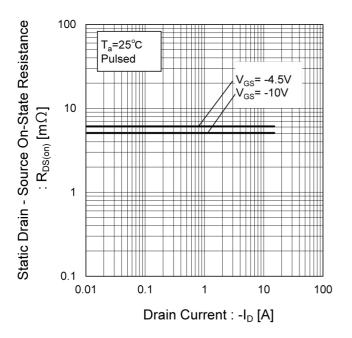


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

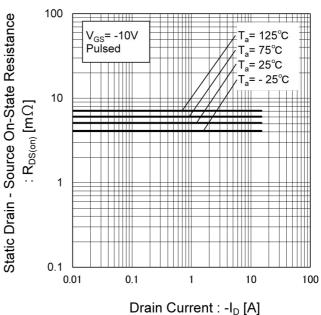


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)

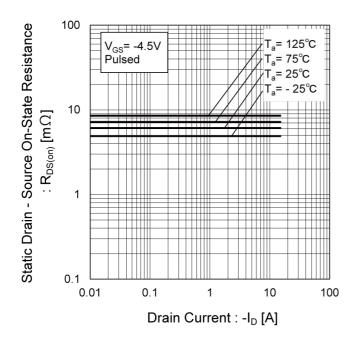


Fig.17 Typical Capacitances vs.

Drain - Source Voltage

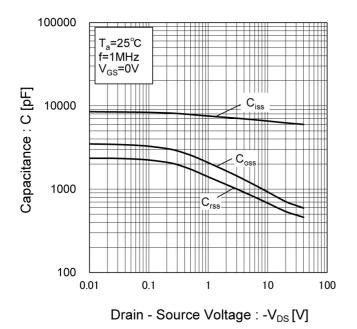


Fig.18 Switching Characteristics

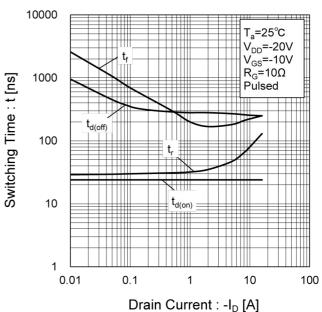


Fig.19 Typical Gate Charge

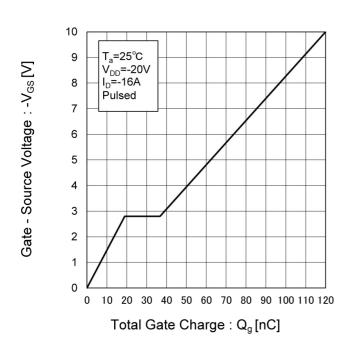
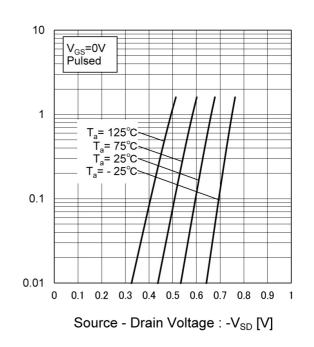


Fig.20 Source Current vs.

Source Drain Voltage



Source Current : -Is [A]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

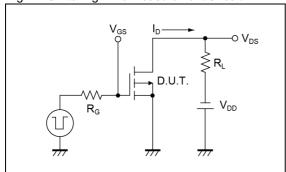


Fig.2-1 Gate Charge Measurement Circuit

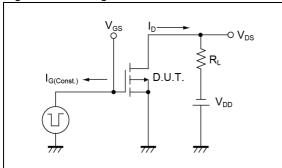


Fig.3-1 Avalanche Measurement Circuit

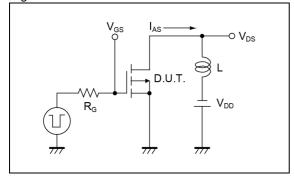


Fig.1-2 Switching Waveforms

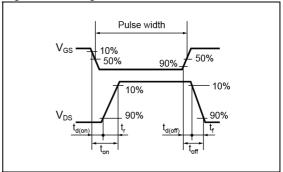


Fig.2-2 Gate Charge Waveform

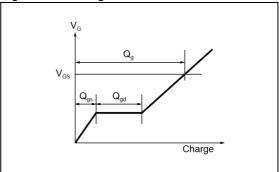
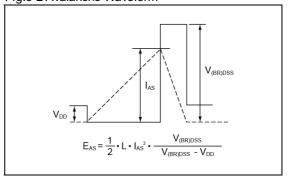
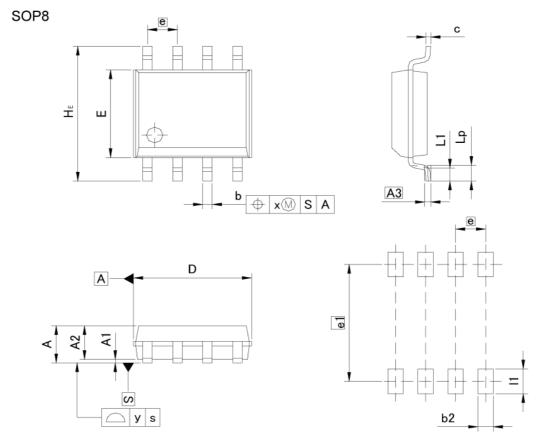


Fig.3-2 Avalanche Waveform



Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	-	1.75	_	0.069
A1	0.	15	0.0	006
A2	1.40	1.60	0.055	0.063
A3	0.25		0.0	10
b	0.30	0.50	0.012	0.020
С	0.10	0.30	0.004	0.012
D	4.80	5.20	0.189	0.205
E	3.75	4.05	0.148	0.159
е	1.3	27	0.050	
HE	5.70	6.30	0.224	0.248
L1	0.40	0.60	0.016	0.024
Lp	0.65	0.85	0.026	0.033
х	0.15		0.0	006
У	0.10		0.0	004
12127	MILIM	ETERS	INC	HES
DIM		MAN	14751	MAN

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
b2	-	0.65	-	0.026	
e1	5.	15	0.2	03	
l1	-,7	1.15	- 1	0.045	

Dimension in mm/inches



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 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
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- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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